

FGW50N60VD

Discrete IGBT

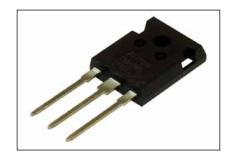
Discrete IGBT (High-Speed V series) 600V / 50A

■ Features

Low power loss Low switching surge and noise High reliability, high ruggedness (RBSOA, SCSOA etc.)

Applications

Inverter for Motor drive AC and DC Servo drive amplifier Uninterruptible power supply

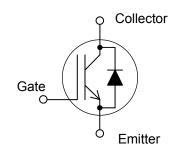


■ Equivalent circuit

■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at T_c=25°C unless otherwise specified)

Items	Symbols	Characteristics	Units	Remarks
Collector-Emitter voltage	Vces	600	V	
Gate-Emitter voltage	V _{GES}	±20	V	
DC Collector Current	Ic@25	85	Α	Tc=25°C, Tj=150°C
	Ic@100	50	Α	Tc=100°C, Tj=150°C
Pulsed Collector Current	I _{CP}	100	Α	Note *1
Turn-Off Safe Operating Area	-	100	Α	Vce≤600V, Tj≤175°C
Diode Forward Current	F@25	70	Α	
	F@100	35	Α	
Diode Pulsed Current	I _{FP}	100	Α	Note *1
Short Circuit Withstand Time	tsc	10	μs	Vcc≤320V, VgE=15V Tj≤150°C
IGBT Max. Power Dissipation	P _{D_IGBT}	360	W	Tc=25°C
FWD Max. Power Dissipation	P _{D_FWD}	200	٧V	Tc=25°C
Operating Junction Temperature	T _j	-40~+175	ç	
Storage Temperature	T _{stg}	-55~+175	°C	



Note *1 : Pulse width limited by Tjmax.

● Electrical characteristics (at T_j= 25°C unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Unit	
	Symbols	Conditions	min.	typ.	max.	Unit	
Collector-Emitter Breakdown Voltage	V _{(BR)CES}	Ic = 250μA, V _{GE} = 0V	600	-	-	V	
Zero Gate Voltage Collector Current	Ices	V _{CE} = 600V, V _{GE} = 0V	-	-	250	μA	
Zero Gate Voltage Collector Current	ICES	I _j =1/5°C	-	-	10	mA	
Gate-Emitter Leakage Current	I _{GES}	$V_{CE} = 0V$, $V_{GE} = \pm 20V$	-	-	200	nA	
Gate-Emitter Threshold Voltage	V _{GE (th)}	$V_{CE} = +20V, I_{C} = 50mA$	6.2	6.7	7.2	V	
Collector-Emitter Saturation Voltage	V _{CE} (sat)	$V_{GE} = +15V$, $I_{C} = 50A$ $T_{I} = 175^{\circ}C$ $T_{I} = 175^{\circ}C$	-	1.60 2.1	2.05	V	
Input Capacitance	Cies	V _{CE} =25V	-	2900	_		
Output Capacitance	Coes	V _{GE} =0V	_	215	-	pF	
Reverse Transfer Capacitance	Cres	f=1MHz	_	175	-	μ.	
Gate Charge	Q _G	V _{CC} = 400V I _C = 50A V _{GE} = 15V	-	360	-	nC	
Turn-On Delay Time	t _{d(on)}	T _j = 25°C	-	45	-	i	
Rise Time	tr	Vcc = 400V	-	90	-	ns	
Turn-Off Delay Time	t _{d(off)}	Ic = 50A	-	310	-		
Fall Time	tr	V _{GE} = 15V	-	55	-	<u> </u>	
Turn-On Energy	Eon	$R_G = 10\Omega$	-	2.4	-		
Turn-Off Energy	E _{off}	L = 500µH Energy loss include "tail" and FWD reverse recovery.	-	1.4	-	mJ	
Turn-On Delay Time	t _{d(on)}	T _j = 175°C	-	45	-		
Rise Time	tr	V _{cc} = 400V	-	100	-		
Turn-Off Delay Time	t _{d(off)}	Ic = 50A	-	340	-	ns	
Fall Time	tr	V _{GE} = 15V	- 60 -				
Turn-On Energy	Eon	$R_G = 10\Omega$	-	4.1	-		
Turn-Off Energy	E _{off}	L = 500µH Energy loss include "tail" and FWD reverse recovery.	-	2.0	-	mJ	
Forward Voltage Drop	VF	I _F =35A T _j =25°C	-	1.5	1.95	V	
To Hara Foliage Drop	V F	I _j =1/5°C	-	1.3	-	V	
Diode Reverse Recovery Time	t _{rr1}	Vcc=30V I _F = 3.5A -di/dt=200A/μs	-	50	65	ns	
Diode Reverse Recovery Time	t rr2	Vcc=400V I⊧=35A	-	0.31	-	μs	
Diode Reverse Recovery Charge	Qrr	-di _F /dt=200A/μs T _I =25°C	-	0.75	-	μC	

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http://www.fujielectric.com/products/semiconductor/

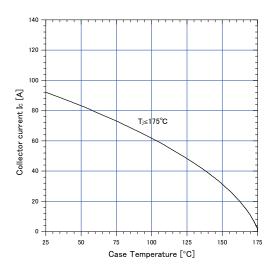
Items	Symbols Conditions		Characteristics			Unit
items	Symbols	Conditions	min.	typ.	max.	Unit
Diode Reverse Recovery Time	t _{rr2}	Vc=400V I⊧=35A	-	0.49	-	μs
Diode Reverse Recovery Charge	Qrr	-di⊧/dt=200A/μs T.=175°C	-	3.3	-	μC

● Thermal resistance

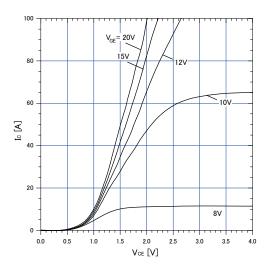
Items	Symbols		Unit		
items	Symbols	min.	typ.	max.	Oilit
Thermal Resistance, Junction-Ambient	R _{th(j-a)}	-	-	50	
Thermal Resistance, IGBT Junction to Case	R _{th(j-c)_IGBT}	-	-	0.417	°C/W
Thermal Resistance, FWD Junction to Case	R _{th(j-c)_FWD}	-	-	0.735	

■ Characteristics (Representative)

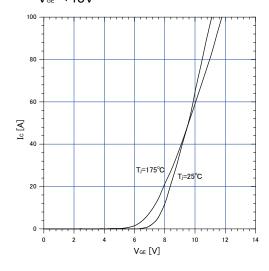
Graph.1 DC Collector Current vs T_c $V_{ce} \ge +15V$, $T_i \le 175$ °C



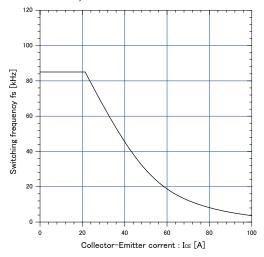
Graph.3 Typical Output Characteristics (V_{CE} - I_{C}) T_{J} =25°C



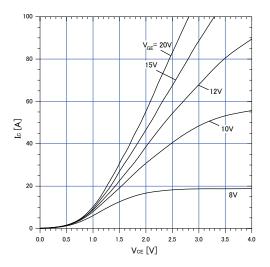
Graph.5 Typical Transfer Characteristics V_{GE} =+15V



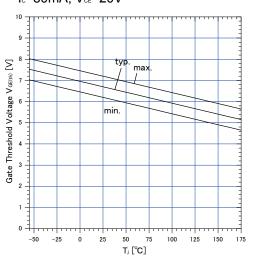
Graph.2 Collector Current vs. switching frequency V_{og} =+15V, T_{o} ≤175°C, V_{co} =400V, D=0.5, R_{o} =10 Ω , T_{o} =100°C



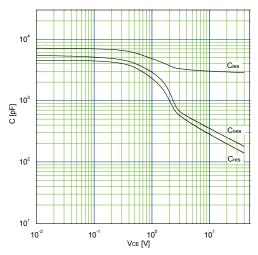
Graph.4
Typical Output Characteristics (V_{cE}-I_c)
T_i=175°C



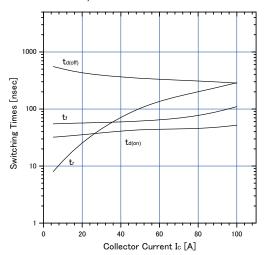
Graph.6
Gate Threshold Voltage vs. T_i
I_c=50mA, V_{cr}=20V



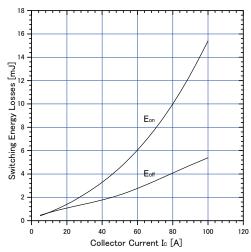
Graph.7 Typical Capacitance V_{s∈}=0V, f=1MHz, T_i=25°C



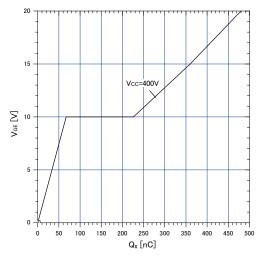
Graph.9 Typical switching time vs. I_c T_j =175°C, V_{cc} =400V, L=500 μ H V_{ce} =15V, R_c =10 Ω



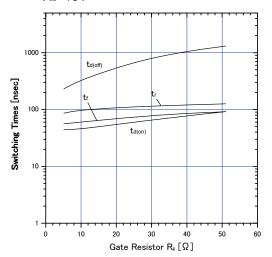
Graph.11 Typical switching losses vs. I_c T_i=175°C, V_{cc} =400V, L=500 μ H V_{ce} =15V, R_c =10 Ω



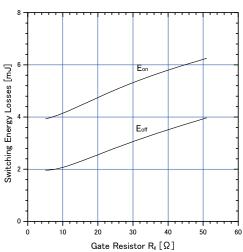
Graph.8 Typical Gate Charge V∞=400V, I₀=50A, T,=25°C



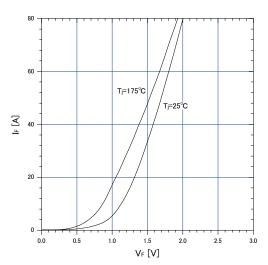
Graph.10 Typical switching time vs. $R_{\rm s}$ T₁=175°C, $V_{\rm cc}$ =400V, $I_{\rm c}$ =50A, L=500 μ H $V_{\rm ce}$ =15V



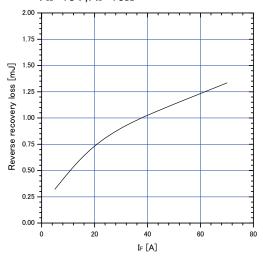
Graph.12 Typical switching losses vs. $R_{\rm G}$ T_J=175°C, V_{CC}=400V, I_C=50A, L=500 μ H V_{CE}=15V



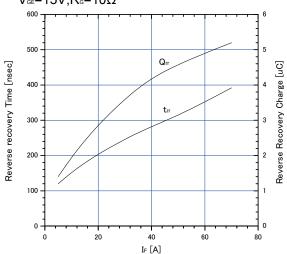
Graph.13 FWD Forward voltage drop (V_F-I_F)



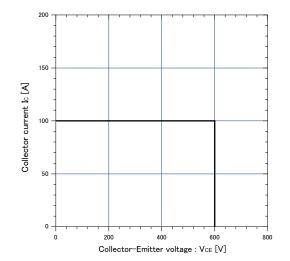
Graph.15 Typical reverse recovery loss vs. I_F T_i =175°C, V_{cc} =400V,L=500 μ H V_{ce} =15V, R_c =10 Ω



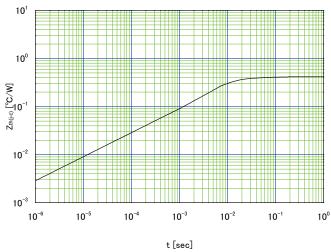
Graph.14 Typical reverse recovery characteristics vs. I_{F} T_j=175°C, V_{cc}=400V, L=500 μ H, V_{cE}=15V,R_c=10 Ω



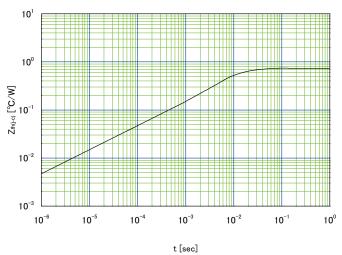
Graph.16 Reverse biased Safe Operating Area $T_1 \le 175^{\circ}C$, $V_{\text{o}\text{E}} = +15 \text{V}/0 \text{V}$, $R_{\text{o}} = 10 \Omega$



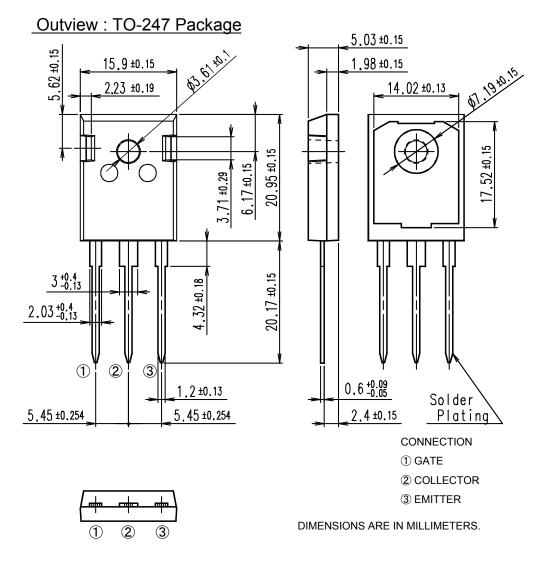
Graph.17
Transient thermal resistance of IGBT



Graph.18
Transient thermal resistance of FWD



■ Outline Drawings, mm



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